# FC591301

# Silicon N-channel MOS FET

For switching circuits

### Overview

FC591301 is N-channel dual type small signal MOS FET employed small size surface mounting package.

### ■ Features

• Low drain-source ON resistance:  $R_{DS(on)}$  typ. =  $2 \Omega (V_{GS} = 4.0 \text{ V})$ 

• High-speed switching

• Small size surface mounting package: SSMini5-F4-B

• Contributes to miniaturization of sets, reduction of component count.

• Eco-friendly Halogen-free package

### Packaging

FC5913010R Embossed type (Thermo-compression sealing): 8000 pcs / reel (standard)

## ■ Absolute Maximum Ratings $T_a = 25$ °C

	Parameter	Symbol	Rating	Unit
FET1 FET2	Drain-source surrender voltage	V <sub>DSS</sub>	30	V
	Gate-source surrender voltage	V <sub>GSS</sub>	±12	V
	Drain current	$I_{\mathrm{D}}$	100	mA
	Peak drain current	$I_{DP}$	200	mA
Overall	Total power dissipation	$P_{T}$	125	mW
	Channel temperature	T <sub>ch</sub>	150	°C
	Storage temperature	T <sub>stg</sub>	-55 to +150	°C

### ■ Package

• Code

SSMini5-F4-B

Package dimension clicks here.→

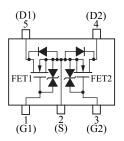
• Pin Name

1: Gate (FET1) 4: Drain (FET2) 2: Source (FET1/2) 5: Drain (FET1)

3: Gate (FET2)

■ Marking Symbol: V3

### ■ Internal Connection



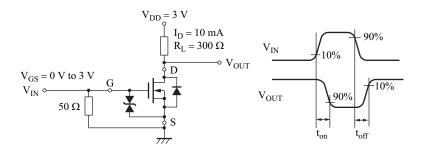
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# ■ Electrical Characteristics $T_a = 25$ °C±3°C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Drain-source surrender voltage	V <sub>DSS</sub>	$I_D = 1 \text{ mA}, V_{GS} = 0$	30			V
Drain-source cutoff current	$I_{DSS}$	$V_{DS} = 30 \text{ V}, V_{GS} = 0$			1.0	μΑ
Gate-source cutoff current	$I_{GSS}$	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0$			±10	μА
Gate threshold voltage	V <sub>TH</sub>	$I_D = 1.0 \mu A, V_{DS} = 3.0 \text{ V}$	0.5	1.0	1.5	V
Drain-source ON resistance	R <sub>DS(on)</sub>	$I_D = 10 \text{ mA}, V_{GS} = 2.5 \text{ V}$		3	6	Ω
Diani-source On Tesistance		$I_D = 10 \text{ mA}, V_{GS} = 4.0 \text{ V}$		2	3	
Forward transfer admittance	Yfs	$I_D = 10 \text{ mA}, V_{DS} = 3.0 \text{ V}$	20	55		mS
Short-circuit input capacitance (Common source)	C <sub>iss</sub>			12		pF
Short-circuit output capacitance (Common source)	C <sub>oss</sub>	$V_{DS} = 3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$		7		pF
Reverse transfer capacitance (Common source)	C <sub>rss</sub>			3		pF
Turn-on time *	t <sub>on</sub>	$V_{DD} = 3 \text{ V}, V_{GS} = 0 \text{ V to 3 V},$ $I_D = 10 \text{ mA}$		100		ns
Turn-off time *	t <sub>off</sub>	$V_{DD} = 3 \text{ V}, V_{GS} = 3 \text{ V to } 0 \text{ V},$ $I_D = 10 \text{ mA}$		100		ns

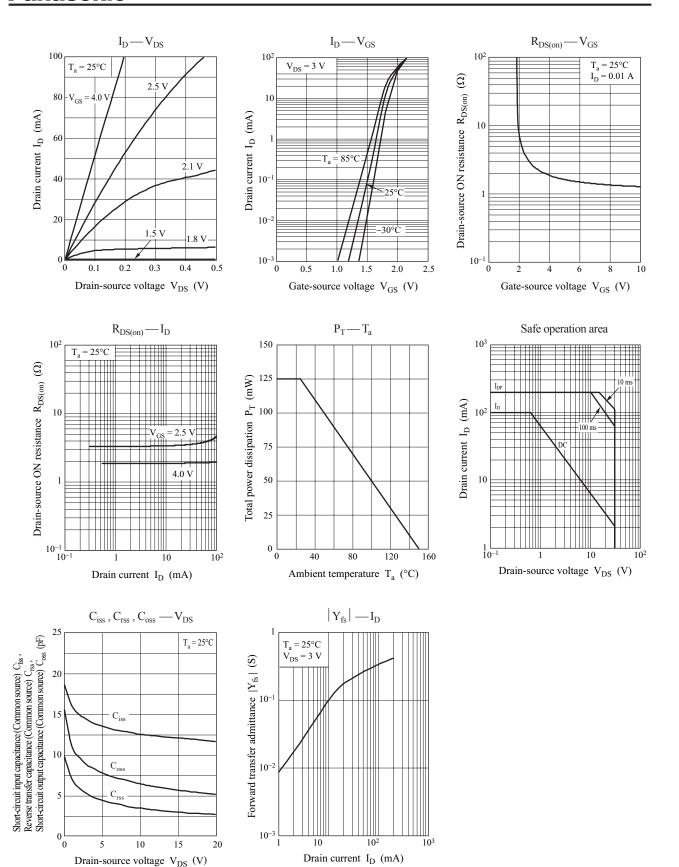
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. \*: Test circuit



2 Ver. BED

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